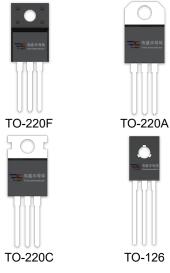


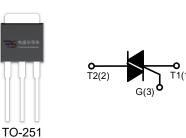
DESCRIPTION:

The BT136-600F SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.



MAIN FEATURES

Symbol	Value	Unit
I _{T(RMS)}	4	А
V _{DRM} /V _{RRM}	600/800	V



ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T _{stg}	-40-150	$^{\circ}$
Operating junction temperature range		Tj	-40-125	$^{\circ}\!\mathbb{C}$
Repetitive peak	off-state voltage(Tj=25℃)	V_{DRM}	600/800	V
Repetitive peak	reverse voltage(T _j =25℃)	V_{RRM}	600/800	V
Non repetitive surge peak Off-state voltage		V _{DSM}	V _{DRM} + 100	V
Non repetitive peak reverse voltage		V _{RSM}	V _{RRM} + 100	V
RMS on-state current	TO-251/ TO-220A(Non-Ins) /TO-220C (Tc=105°C) TO-220A(Ins)/ TO-220F(Ins) (Tc=100°C) TO-202-3/ TO-126/SOT-82 (Tc=95°C)	I _{T(RMS)}	4	А



Non repetitive surge peak on-state current (full cycle, F=50Hz)		I _{TSM}	35	А
I ² t value for fusing (tp=10ms)		l²t	6.1	A ² s
Critical rate of rise of on-state	I - II -III	dI/dt	50	A/µs
current (I _G =2×I _{GT})	IV	dl/dt	10	
Peak gate current		Ідм	2	Α
Average gate power dissipation		P _{G(AV)}	0.5	W
Peak gate power		P _{GM}	5	W

ELECTRICAL CHARACTERISTICS (T_j=25 °C unless otherwise specified)

Symbol	Test Condition	Quadrant		Value			Hoit	
	rest Condition			Т	D	Е	F	Unit
lo-	V _D =12V	I - II -III	MAX	5	5	10	25	mA
lgт		IV		5	10	25	70	
V _{GT}		ALL	MAX	1.3				V
V _{GD}	$V_D=V_{DRM}T_j=125$ °C RL=3.3KΩ	ALL	MIN	0.2			V	
1.	I _G =1.2I _{GT}	I -III	MAX	10	20	30	40	mA
IL		II -IV		15	35	45	60	
Ін	Iτ=100mA		MAX	5	15	25	30	mA
dV/dt	V _D =2/3V _{DRM} Gate Open T _j =125℃		MIN	20	50	100	150	V/µs
(dV/dt)c	(dI/dt)c=1.7A/ms T _j =125℃		MIN	0.1	0.1	0.5	5	V/µs

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V _{TM}	I _{тм} =5.5A tp=380µs	T _j =25℃	1.6	V
I _{DRM}	VD=VDRM VR=VRRM	T _j =25℃	5	μA
I _{RRM}		T _j =125℃	0.5	mA



THERMAL RESISTANCES

Symbol	Param	Value	Unit	
R _{th(j-c)}	junction to case(AC)	TO-251	2.8	
		TO-220A(Ins)	3.5	°C/W
		TO-220A(Non-Ins)/ TO-220C	2.5	
		TO-220F(Ins)	3.3	
		TO-126/SOT-82	3.7	
		TO-202-3	3.9	



FIG.1: Maximum power dissipation versus RMS on-state current

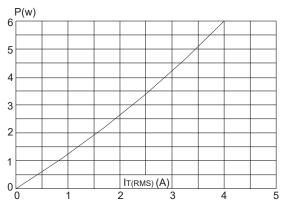


FIG.3: Surge peak on-state current versus number of cycles

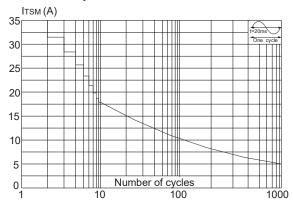


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms and corresponding value of I^2t (I - II - III : dI/dt < 50A/ μ s; IV:dI/dt < 10A/ μ s)

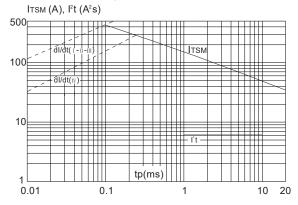


FIG.2: RMS on-state current versus case temperature

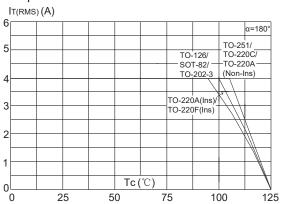


FIG.4: On-state characteristics (maximum values)

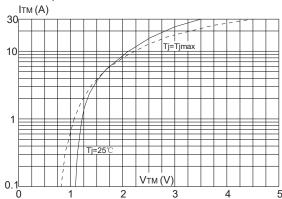


FIG.6: Relative variations of gate trigger current versus junction temperature

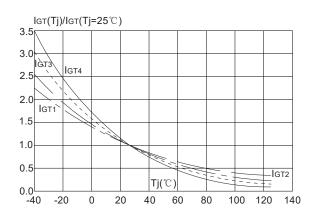




FIG.7: Relative variations of holding current versus junction temperature

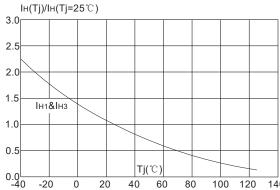


FIG.8: Relative variations of latching current versus junction temperature

